

Part Description

The BTN6037 is a silicon BJT transistor available in bare die form and well suited for use in general purpose switching and amplifier applications. PNP Complement is BTP6037.

Key Parameters:

- · VCBO = 40V
- · VCEO = 32V
- · VEBO = 5V
- hFE = 82-390 @ VCE = 3V, IC = 0.5A
- · VCE(Sat) = 0.8V @ IC = 2A, IB = 200mA
- fT = 270 MHz @ VCE = 5V, IE = 0A
- · COBO = 14pF @ VCB = 10V

Features

Low VCE(sat). Designed to provide performance equivalent to ROHM 2SD1766

Die Size (Unsawn)

700µm X 700µm, 28 Mils X 28 Mils



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